

Device Modeling Report

COMPONENTS:

DIODE/ SCHOOTTKY RECTIFIER / STANDARD

PART NUMBER: 11EQ09

MANUFACTURER: NIEC

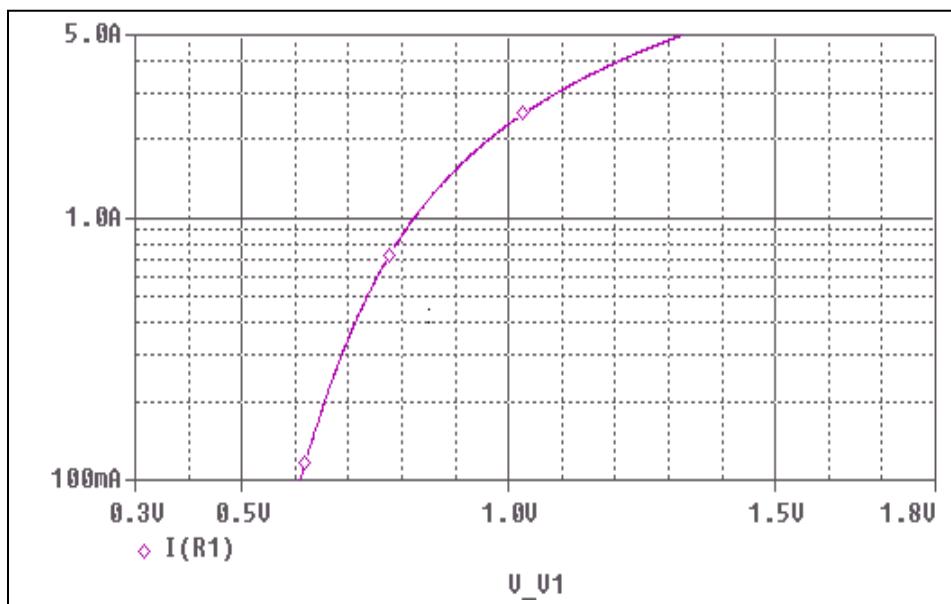


Bee Technologies Inc.

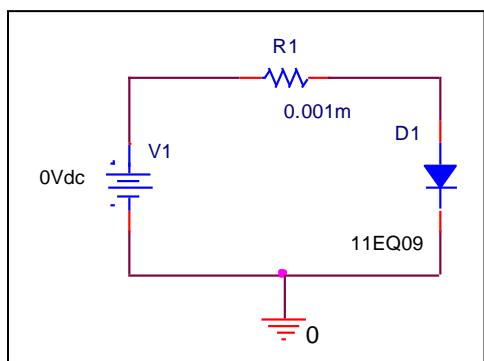
PSpice model parameter	Model description
IS	Saturation Current
N	Emission Coefficient
RS	Series Resistance
IKF	High-injection Knee Current
CJO	Zero-bias Junction Capacitance
M	Junction Grading Coefficient
VJ	Junction Potential
ISR	Recombination Current Saturation Value
BV	Reverse Breakdown Voltage(a positive value)
IBV	Reverse Breakdown Current(a positive value)
TT	Transit Time
EG	Energy-band Gap

Forward Current Characteristic

Circuit Simulation Result

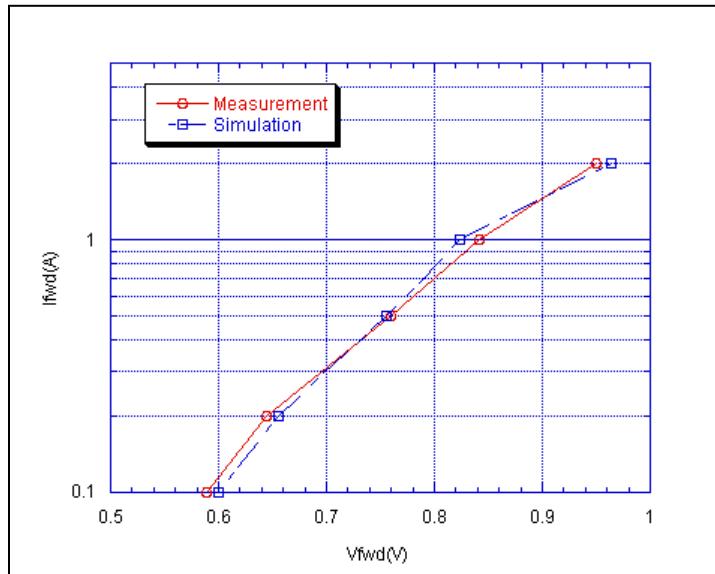


Evaluation Circuit



Comparison Graph

Circuit Simulation Result

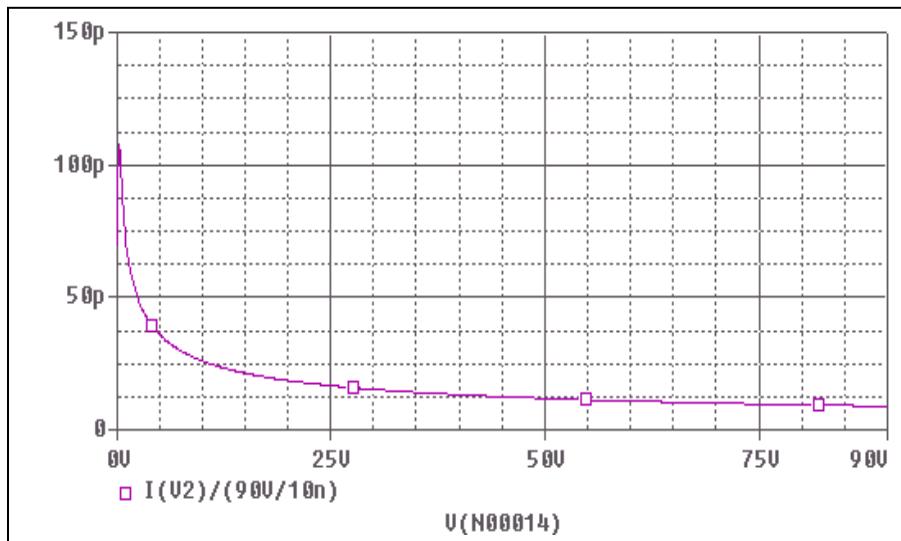


Simulation Result

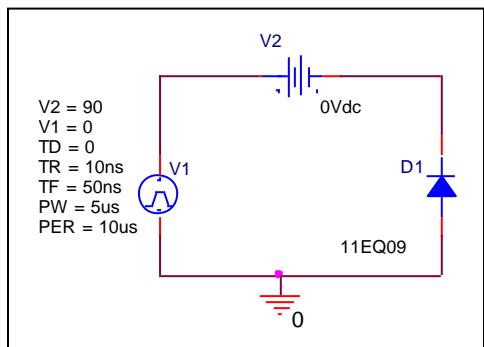
$I_{fwd}(A)$	$V_{fwd}(V)$ Measurement	$V_{fwd}(V)$ Simulation	%Error
0.1	0.59	0.60	1.87
0.2	0.65	0.66	1.55
0.5	0.76	0.76	-0.66
1	0.84	0.82	-2.26
2	0.95	0.96	1.47

Junction Capacitance Characteristic

Circuit Simulation Result

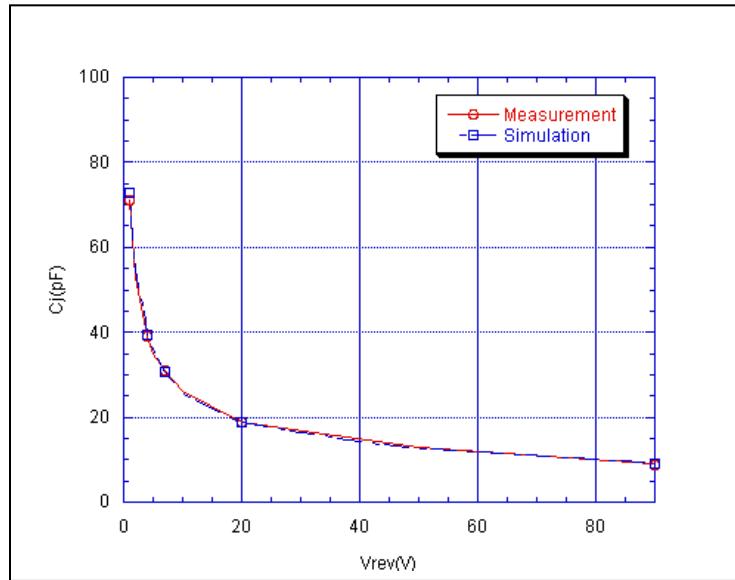


Evaluation Circuit



Comparison Graph

Circuit Simulation Result



Simulation Result

Vrev(V)	Cj(pF) Measurement	Cj(pF) Simulation	%Error
1	71.00	73.00	2.82
2	53.00	54.77	3.34
4	39.00	39.53	1.36
5	35.00	35.93	2.66
7	31.00	30.76	-0.77
10	26.00	25.80	-0.77
20	19.00	18.81	-1.00
50	13.00	12.76	-1.85
90	8.90	9.00	1.12